

MOS FIELD EFFECT TRANSISTOR μ PA2708TP

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The μ PA2708TP which has a heat spreader is N-channel MOS Field Effect Transistor designed for DC/DC converter and power management applications of notebook computer.

FEATURES

• Low on-state resistance

 $R_{DS(on)1}$ = 5.5 $m\Omega$ MAX. (VGS = 10 V, I_D = 9.0 A)

 $R_{DS(on)2}$ = 7.5 m Ω MAX. (V_{GS} = 4.5 V, I_D = 9.0 A)

- Low Ciss: Ciss = 4700 pF TYP. (VDS = 10 V, VGS = 0 V)
- Small and surface mount package (Power HSOP8)

ORDERING INFORMATION

| PART NUMBER | PACKAGE |
|-----------------------|-------------|
| μ PA2708TP-E1 | Power HSOP8 |
| μ PA2708TP-E1-AZ Note | Power HSOP8 |
| μ PA2708TP-E2 | Power HSOP8 |
| μ PA2708TP-E2-AZ Note | Power HSOP8 |

Note Pb-free (This product does not contain Pb in external electrode.)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

| Drain to Source Voltage (Vgs = 0 V) | VDSS | 30 | V |
|-------------------------------------|-----------------------|-------------|----|
| Gate to Source Voltage (VDS = 0 V) | Vgss | ±20 | V |
| Drain Current (DC) | ID(DC) | ±40 | Α |
| Drain Current (pulse) Note1 | I _{D(pulse)} | ±68 | Α |
| Total Power Dissipation (Tc = 25°C) | P _{T1} | 34 | W |
| Total Power Dissipation Note2 | P _{T2} | 4.3 | W |
| Channel Temperature | Tch | 150 | °C |
| Storage Temperature | T _{stg} | -55 to +150 | °C |
| Single Avalanche Current Note3 | las | 17 | Α |
| Single Avalanche Energy Note3 | Eas | 28.9 | mJ |

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- 2. Mounted on glass epoxy board of 1 inch x 1 inch x 0.8 mm, PW =10 sec
- 3. Starting T_{ch} = 25°C, V_{DD} = 15 V, R_G = 25 Ω , L = 100 μ H, V_{GS} = 20 \rightarrow 0 V

THERMAL RESISTANCE

| Channel to Ambient Note | Rth(ch-A) | 96.2 | °C/W |
|-------------------------|-----------|------|------|
| Channel to Case | Rth(ch-C) | 3.68 | °C/W |

Note Mounted on glass epoxy board of 1 inch x 1 inch x 0.8 mm

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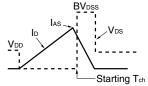
ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--|----------------------|---|------|------|------|------|
| Zero Gate Voltage Drain Current | IDSS | V _{DS} = 30 V, V _{GS} = 0 V | | | 10 | μΑ |
| Gate Leakage Current | Igss | V _{GS} = ±20 V, V _{DS} = 0 V | | | ±100 | nA |
| Gate Cut-off Voltage | V _{GS(off)} | V _{DS} = 10 V, I _D = 1 mA | 1.0 | | 2.5 | V |
| Forward Transfer Admittance Note | y _{fs} | V _{DS} = 10 V, I _D = 9.0 A | 10 | | | S |
| Drain to Source On-state Resistance Note | RDS(on)1 | V _{GS} = 10 V, I _D = 9.0 A | | 4.5 | 5.5 | mΩ |
| | RDS(on)2 | V _{GS} = 4.5 V, I _D = 9.0 A | | 5.6 | 7.5 | mΩ |
| Input Capacitance | Ciss | V _{DS} = 10 V | | 4700 | | pF |
| Output Capacitance | Coss | V _{GS} = 0 V | | 670 | | pF |
| Reverse Transfer Capacitance | Crss | f = 1 MHz | | 340 | | pF |
| Turn-on Delay Time | t _{d(on)} | V _{DD} = 15 V, I _D = 9.0 A | | 19 | | ns |
| Rise Time | tr | V _{GS} = 10 V | | 26 | | ns |
| Turn-off Delay Time | td(off) | R _G = 10 Ω | | 100 | | ns |
| Fall Time | t _f | | | 27 | | ns |
| Total Gate Charge | QG | V _{DD} = 15 V | | 38 | | nC |
| Gate to Source Charge | Qgs | V _{GS} = 5 V | | 13 | | nC |
| Gate to Drain Charge | Q _{GD} | I _D = 17 A | | 12 | | nC |
| Body Diode Forward Voltage Note | V _{F(S-D)} | I _F = 17 A, V _{GS} = 0 V | | 0.8 | | ٧ |
| Reverse Recovery Time | trr | I _F = 17 A, V _{GS} = 0 V | | 33 | | ns |
| Reverse Recovery Charge | Qrr | di/dt = 100 A/μs | | 27 | | nC |
| Gate Resistance | Rg | f = 1 MHz | | 1.2 | | Ω |

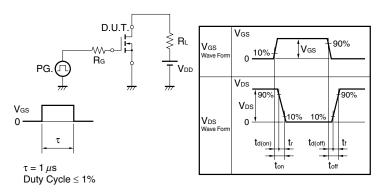
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$\begin{array}{c} \text{D.U.T.} \\ \text{RG} = 25 \ \Omega \\ \text{VGS} = 20 \rightarrow 0 \ \text{V} \end{array}$

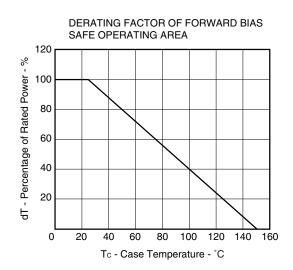


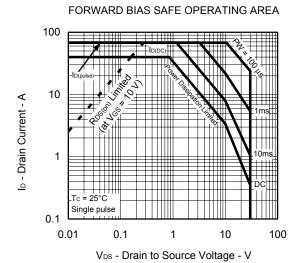
TEST CIRCUIT 2 SWITCHING TIME



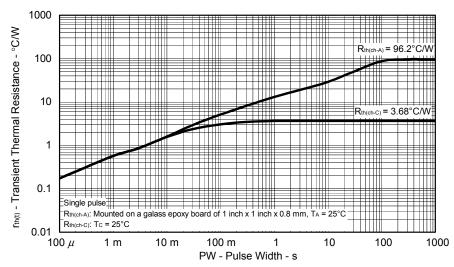
TEST CIRCUIT 3 GATE CHARGE

TYPICAL CHARACTERISTICS (TA = 25°C)

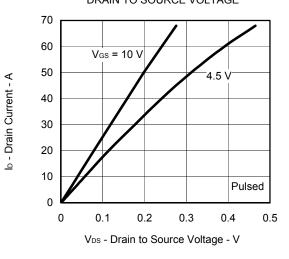




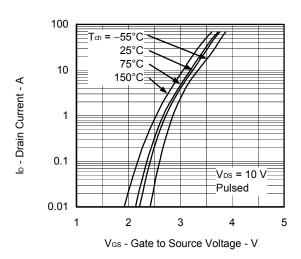
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

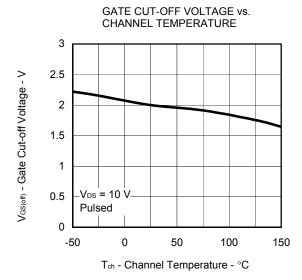


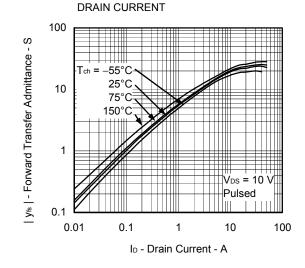
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



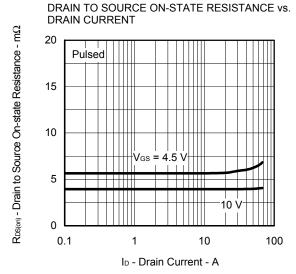
FORWARD TRANSFER CHARACTERISTICS

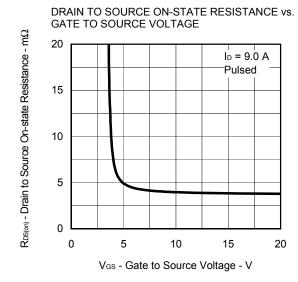


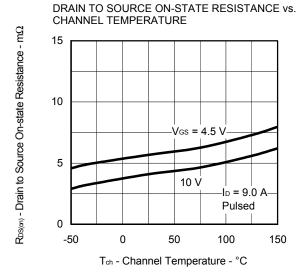


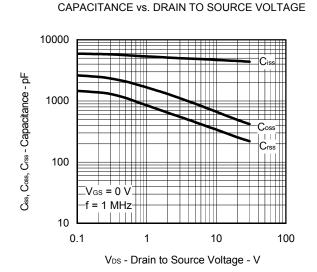


FORWARD TRANSFER ADMITTANCE vs.



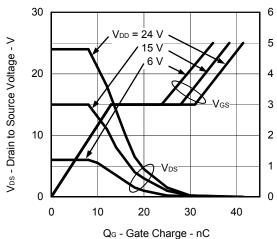




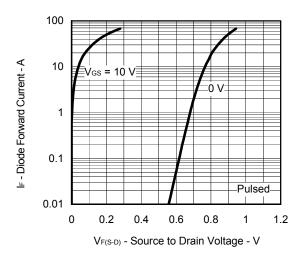


Ves - Gate to Source Voltage - V

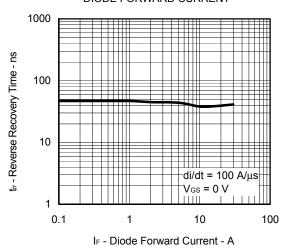
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



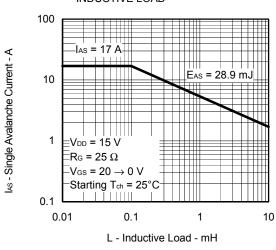
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



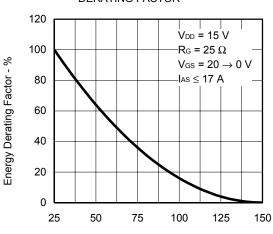
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



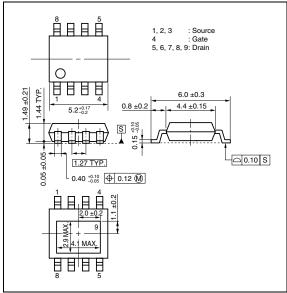
SINGLE AVALANCHE ENERGY DERATING FACTOR



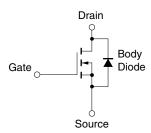
Starting Tch - Starting Channel Temperature - °C

PACKAGE DRAWING (Unit: mm)

Power HSOP8



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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